

• General Description

It combines advanced trench MOSFET technology with a low resistance package to provide extremely low $R_{DS(ON)}$.

• Features

- AEC-Q101 Qualified
- Low $R_{DS(ON)}$ to minimize conductive loss
- High GOX reliability
- Low Thermal resistance

• Application

- BLDC Motor driver
- DC-DC
- Load switch

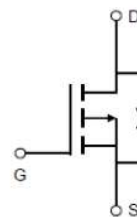
• Ordering Information:

Part NO.	ZMA060P04D
Marking	ZM060P04
Packing Information	REEL TAPE
Basic ordering unit (pcs)	2500

• Absolute Maximum Ratings ($T_C=25^\circ\text{C}$)

Parameter	Symbol	Conditions	Value	Unit
Drain-Source Voltage	V_{DS}		-40	V
Gate-Source Voltage ^①	V_{GS}		±20	V
Continuous Drain Current	I_D	$T_C=25^\circ\text{C}$	-74	A
	I_D	$T_C=75^\circ\text{C}$	-60	A
	I_D	$T_C=100^\circ\text{C}$	-52	A
Pulsed Drain Current	I_{DM}	Pulsed; $t_p \leq 10 \mu\text{s}$; $T_{mb} = 25^\circ\text{C}$;	-296	A
Total Power Dissipation	P_D	$T_C=25^\circ\text{C}$	75	W
Total Power Dissipation	P_D	$T_A=25^\circ\text{C}$	2.4	W
Operating Junction Temperature	T_J		-55 to +175	$^\circ\text{C}$
Storage Temperature	T_{STG}		-55 to +175	$^\circ\text{C}$
Single Pulse Avalanche Energy	E_{AS}	$L=0.1\text{mH}$, $V_{GS}=-10\text{V}$, $R_g=25\Omega$,	180	mJ
		$L=0.5\text{mH}$, $V_{GS}=-10\text{V}$, $R_g=25\Omega$,	378	mJ
ESD Level (HBM)	CLASS 2			

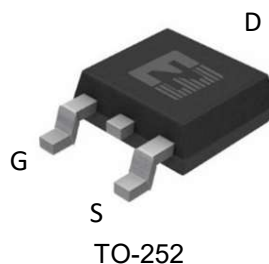
• Product Summary



$$V_{DS} = -40\text{V}$$

$$R_{DS(ON)} = 6.8\text{m}\Omega$$

$$I_D = -74\text{A}$$



•Thermal resistance

Parameter	Symbol	Min.	Typ.	Max.	Unit
Thermal resistance, junction - case	R_{thJC}		-	2	°C/W
Thermal resistance, junction-ambient ^②	R_{thJA}		-	62	°C/W
Soldering temperature	T_{sold}		-	260	°C

•Electronic Characteristics

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-40			V
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=-250\mu A$	-1.3	-1.8	-2.5	V
Drain-Source Leakage Current	I_{DSS}	$V_{GS}=0V, V_{DS}=-40V$			-1.0	μA
Gate- Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$			± 100	nA
Static Drain-source On Resistance	$R_{DS(ON)}$	$V_{GS}=-10V, I_D=-40A$		6.8	8.8	m Ω
		$V_{GS}=-4.5V, I_D=-25A$		10	12	m Ω
Forward Transconductance	g_{FS}	$V_{DS}=-5V, I_{SD}=-10A$		28		S
Diode Forward Voltage	V_{FSD}	$V_{GS}=0V, I_{SD}=-40A$			-1.3	V

•Dynamic characteristics

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input capacitance	C_{iss}	$f=1MHz, V_{DS}=-25V$	-	6210	-	pF
Output capacitance	C_{oss}		-	468	-	
Reverse transfer capacitance	C_{rss}		-	397	-	
Gate Resistance	R_g	$f=1MHz$	-	3		Ω
Total gate charge	Q_g	$V_{DD}=-15V, I_D=-20A, V_{GS}=-10V$	-	106	-	nC
	$Q_g(-4.5v)$		-	51	-	
Gate - Source charge	Q_{gs}		-	13	-	
Gate - Drain charge	Q_{gd}		-	20	-	
Turn-ON Delay time	$t_{D(on)}$	$V_{GS}=-10V, V_{DS}=-15V, R_G=3.3\Omega, I_D=-20A$	-	18	-	ns
Turn-ON Rise time	t_r		-	27	-	ns
Turn-Off Delay time	$t_{D(off)}$		-	105	-	ns
Turn-Off Fall time	t_f		-	45	-	ns



Fig.1 Gate-Charge Characteristics

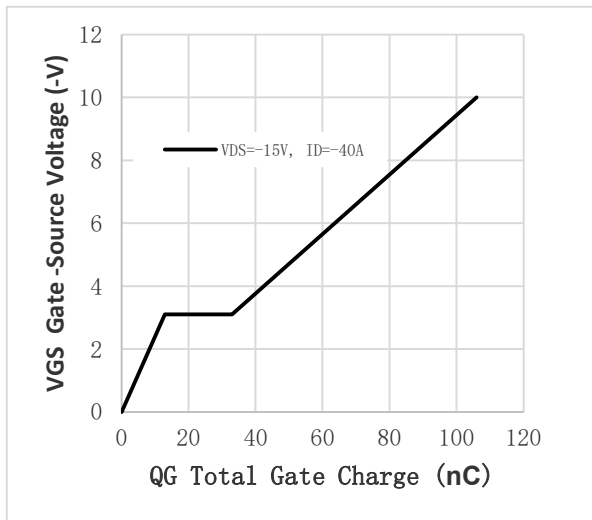


Fig.2 Capacitance Characteristics

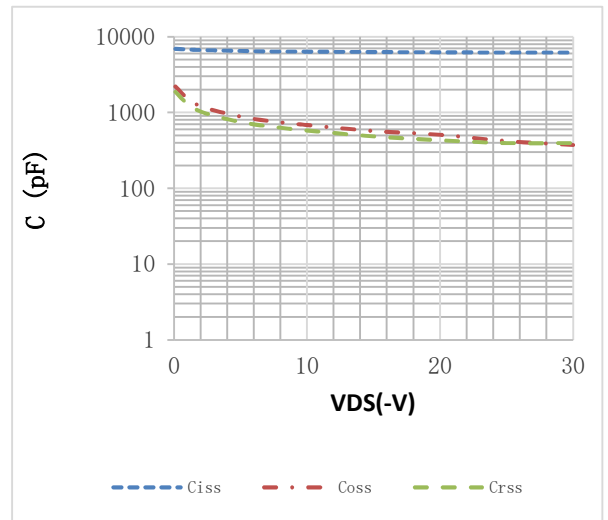


Fig.3 Power Dissipation

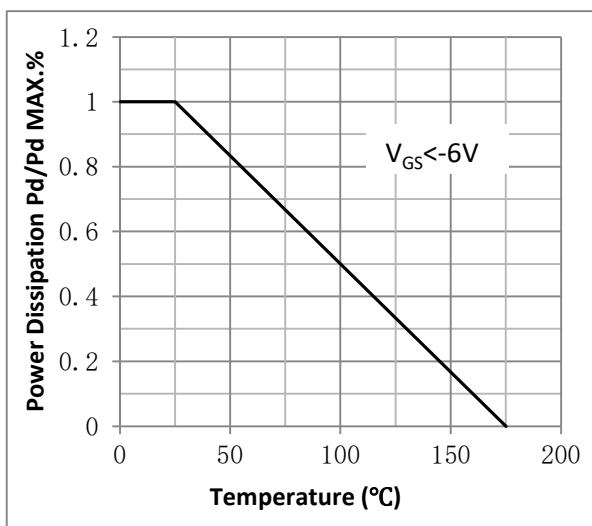


Fig.4 Typical output Characteristics

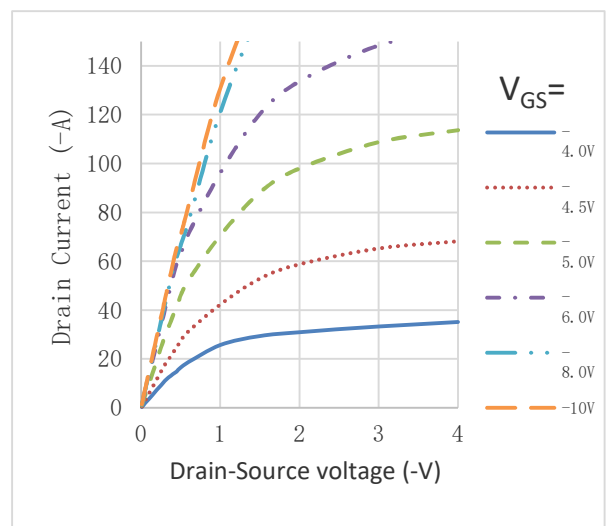


Fig.5 Threshold Voltage V.S Junction Temperature

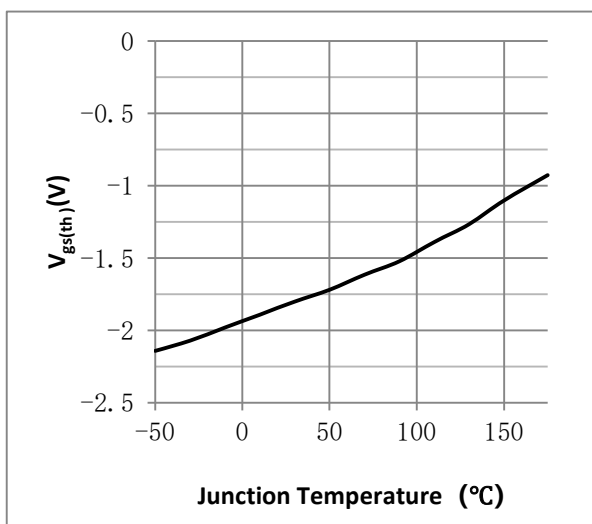


Fig.6 Resistance V.S Drain Current

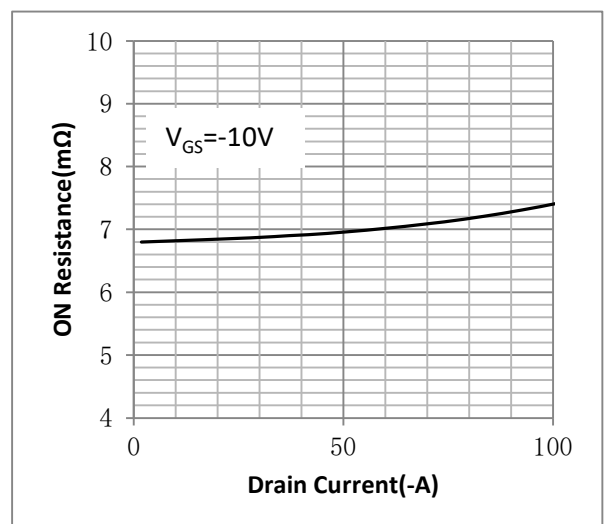


Fig.7 On-Resistance VS Gate Source Voltage

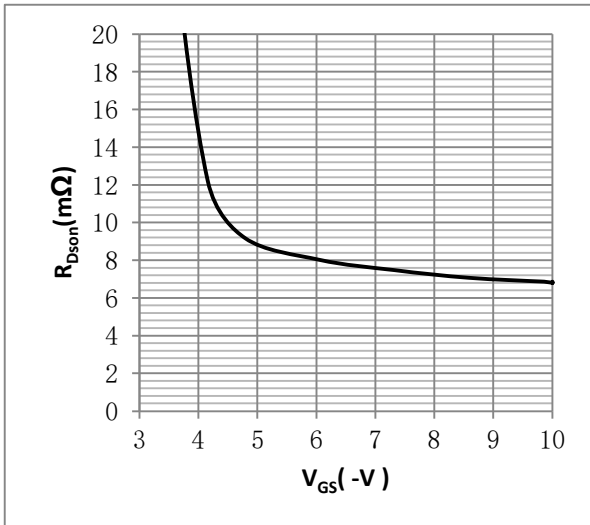


Fig.8 On-Resistance V.S Junction Temperature

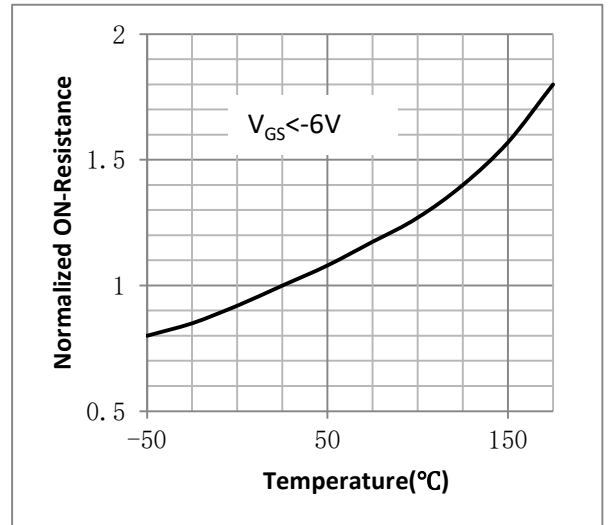


Figure 9. Diode Forward Voltage vs. Current

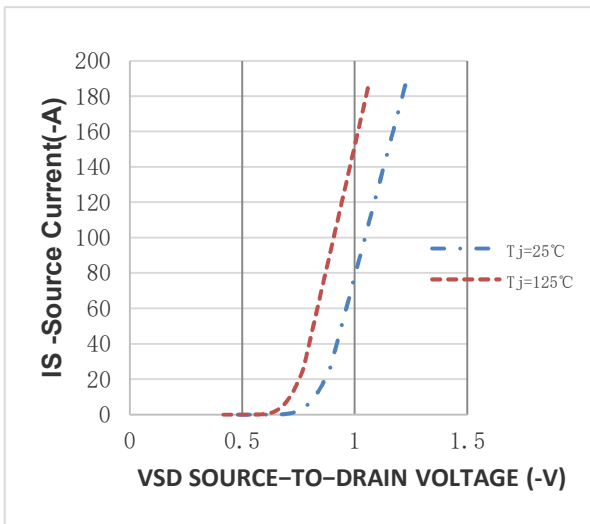


Figure 10. Transfer Characteristics

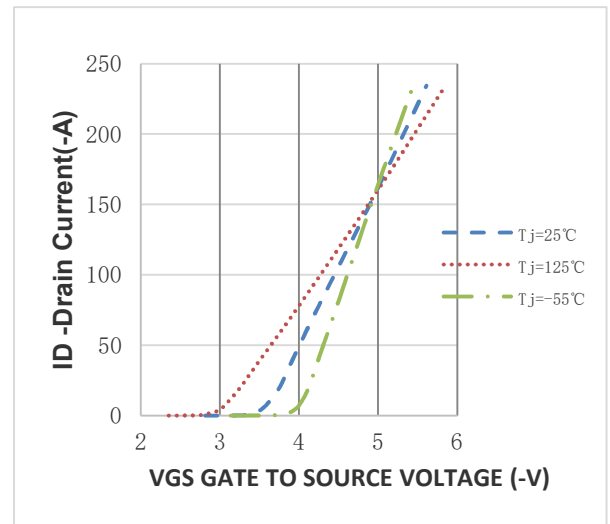


Fig.11 Safe Operating Area

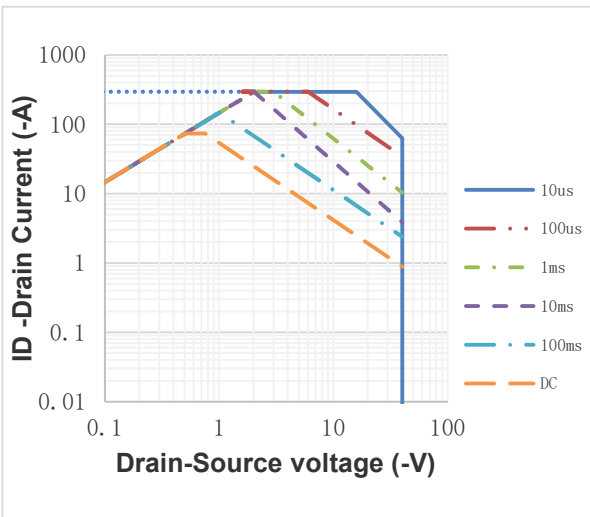
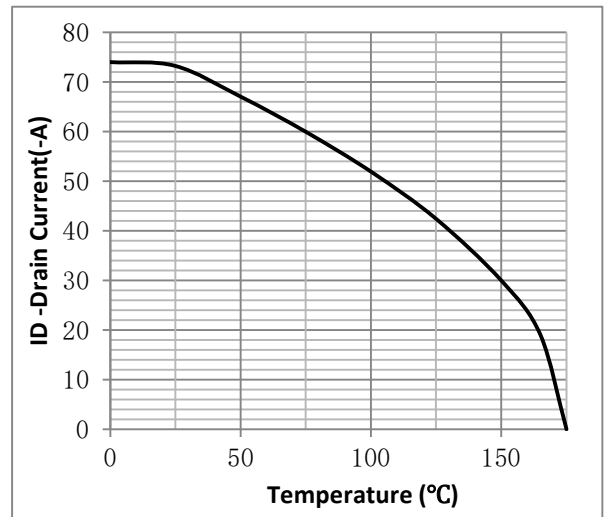
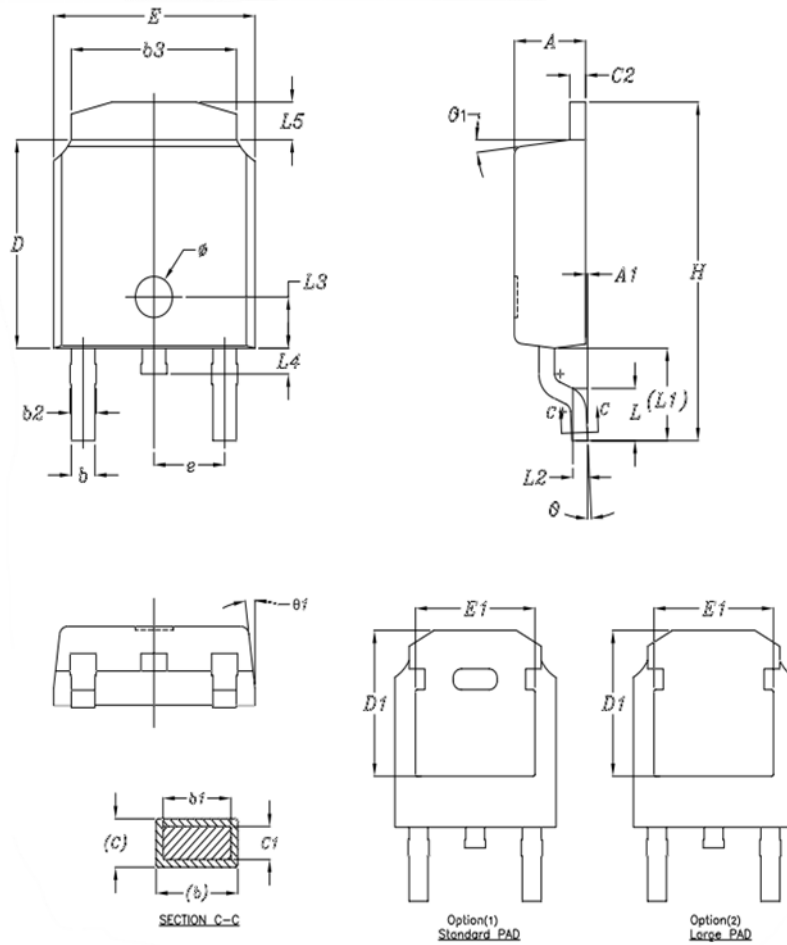


Fig.12 I_D vs. Case Temperature^③

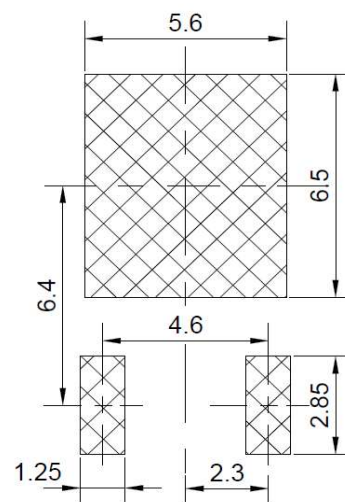


•TO-252 Package Outline



I T E M	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.18	2.39	0.086	0.094
A1	—	0.13	—	0.005
b	0.70	0.89	0.028	0.035
b1	0.70	0.86	0.028	0.034
b2	0.76	1.14	0.030	0.045
b3	4.95	5.46	0.195	0.215
c	0.46	0.61	0.018	0.024
c1	0.41	0.56	0.016	0.022
c2	0.46	0.89	0.018	0.035
D	5.97	6.22	0.235	0.245
D1	5.21	—	0.205	—
E	6.35	6.73	0.250	0.265
E1	4.32	—	0.170	—
e	2.29 BSC		0.090 BSC	
H	9.40	10.41	0.370	0.410
L	1.40	1.78	0.055	0.070
L1	2.60	2.90	0.102	0.114
L2	0.51 BSC		0.020 BSC	
L3	1.65	1.95	0.065	0.077
L4	0.60	0.90	0.024	0.035
L5	0.89	1.27	0.035	0.050
θ	1°	5°	1°	5°
θ1	7° REF		7° REF	
φ	1.20 REF		1.20 REF	

Land Pattern
(Only for Reference)



Note:

- ① Pulse : $V_{GS}=+20V/-20V$, Duty cycle=50%, $T_j=175^{\circ}C$, $t=1000$ hours; For DC , the following test conditions can be passed: $V_{GS}=-20V/+10V$, $T_j=175^{\circ}C$, $t=1000$ hours;
- ② Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate;
- ③ Practically the current will be limited by PCB, thermal design and operating temperature. $V_{GS}=-10V$.

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Revision History

Version	Date	Change
A	2021.5.25	
B	2021.11.7	1.Modified Typical output Characteristics curve
C	2022.9.6	1.Add Reach,HF figure
D	2022.10.30	1.ID modify
E	2023.6.25	Correct VGS&SOA
F	2025.9.2	Update POD.